Features:

- 650V Schottky Diode
- Zero Reverse Recovery Current
- High Frequency Operation
- Positive Temperature Coefficient
- Temperature independent Switching

Benefits:

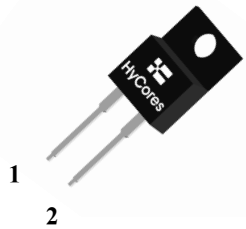
- Unipolar Rectifier
- Minimal switching loss
- Higher Efficiency
- Low cooling requirement

Symbol	Value	Unit
V_{RRM}	650	V
$I_{F\ (Tc=150^oC)}$	10	A
Q_C	36	nC

Applications:

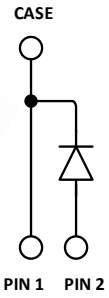
- Switch Mode Power Supply
- Booster diodes in PFC, DC/DC
- AC/DC converters

Outline



TO-220-2FP

Circuit



Maximum Ratings

Symbol	Parameter	Value	Unit	Test Conditions
V_R	DC Peak Reverse Voltage	650	V	T_J =25°C
V_{RRM}	Repetitive Peak Reverse	650	V	T_J =25°C
V_{RSM}	Surge Peak Reverse Voltage	650	V	T_J =25°C
I_F	Continuous Forward Current	31 14 10	A	T_C =25°C T_C =135°C T_C =150°C
I_{FRM}	Repetitive Peak Forward Surge Current	89 80	A	T_C =25°C, T_P=10ms, Half Sine Wave Tc=125°C, T_P =10ms, Half Sine Wave
I_{FSM}	Non-Repetitive Peak Forward Surge Current	119 107	A	T_C =25°C, T_P =10ms, Half Sine Wave Tc=125°C, T_P =10ms, Half Sine Wave
P_D	Power Dissipation	103 34	W	T_C =25°C Tc=125°C
$T_{J,max}$	Operating Junction Temperature	175	°C	
T_{stg}	Storage Temperature Range	-55 to 175	°C	

Thermal characteristics

Symbol	Parameter	Min.	Typ.	Max.	Unit
R_{thJC}	Thermal Resistance		1.46		°C/W

Electrical Characteristics

Symbol	Parameter	Value			Unit	Test Conditions
		Min.	Typ.	Max.		
V_{DC}	DC Blocking Voltage	650			V	I_R = 100μA, T_J = 25°C
V_F	Forward Voltage		1.35 1.6	1.6 1.9	V	I_F = 10A, T_J = 25°C I_F = 10A, T_J = 175°C
I_R	Reverse Current		2 15	50 160	μA	V_R = 650V, T_J = 25°C V_R = 650V, T_J = 175°C
Q_C	Total Capacitive Charge		36		nC	I_F = 10A, dI/dt = 300A/μs T_J = 25°C, V_R = 400V
C	Total Capacitance		646 86 82		pF	V_R = 1V, T_J = 25°C, f = 1 MHz V_R = 200V, T_J = 25°C, f = 1 MHz V_R = 400V, T_J = 25°C, f = 1 MHz

Typical Performance

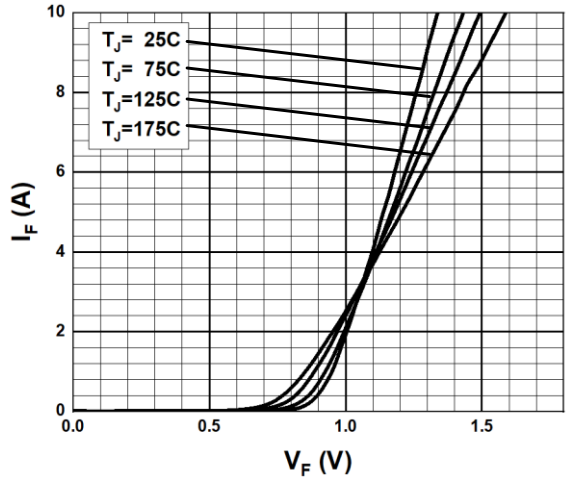


Fig. 1 Forward Characteristics

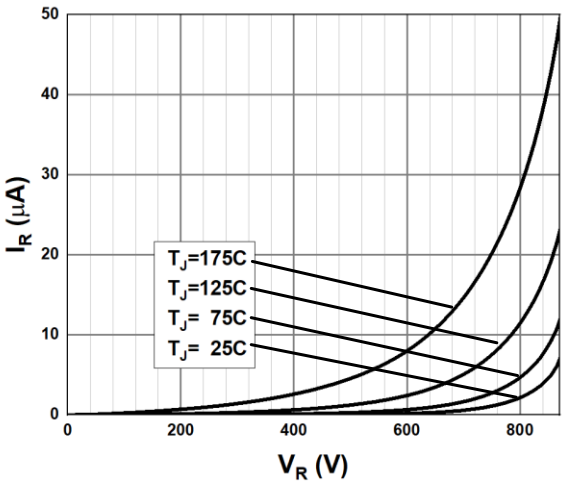


Fig. 2 Reverse Characteristics

Typical Performance

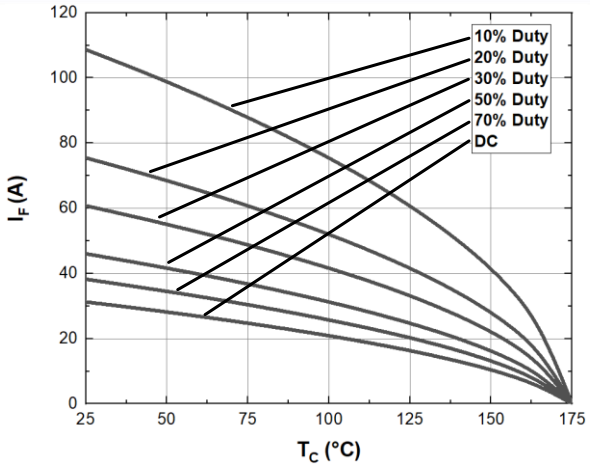


Fig. 3 Current Derating

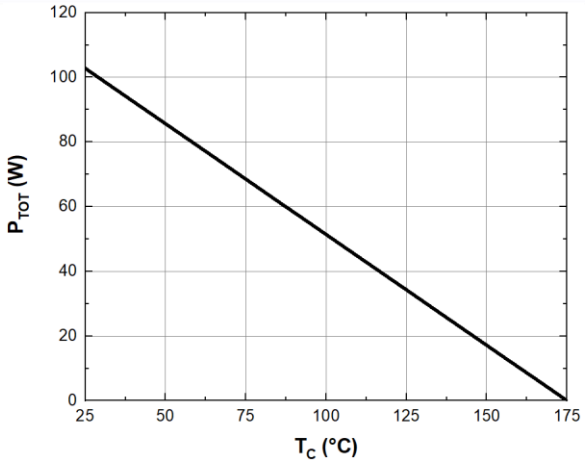


Fig. 4 Power Derating

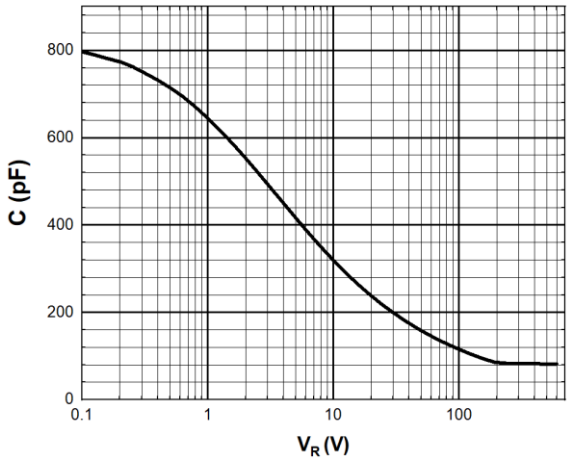


Fig. 5 Capacitance vs. Reverse Voltage

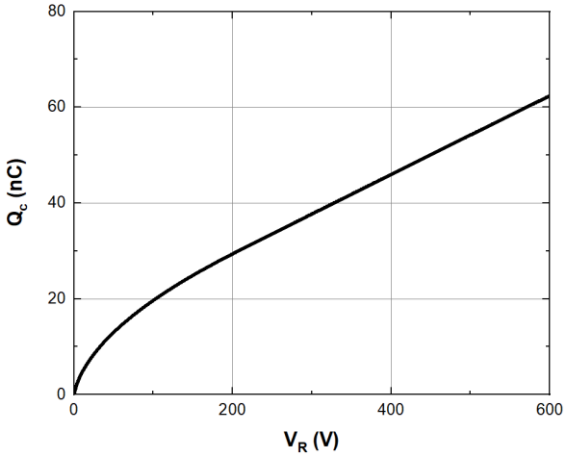


Fig. 6 Recovery Charge vs. Reverse Voltage

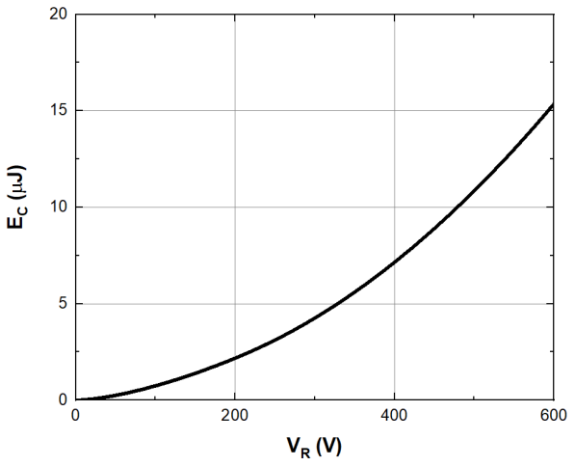


Fig. 7 Capacitance stored Energy

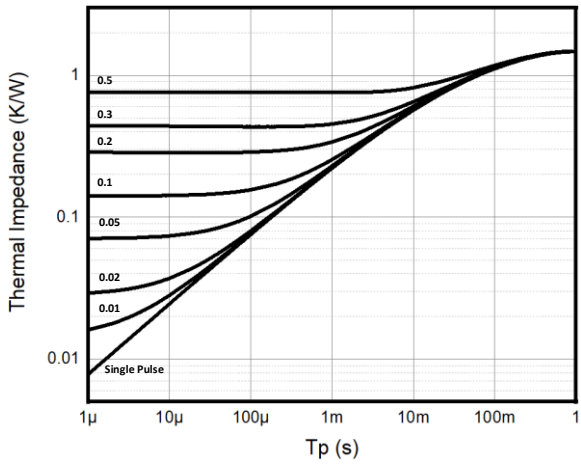
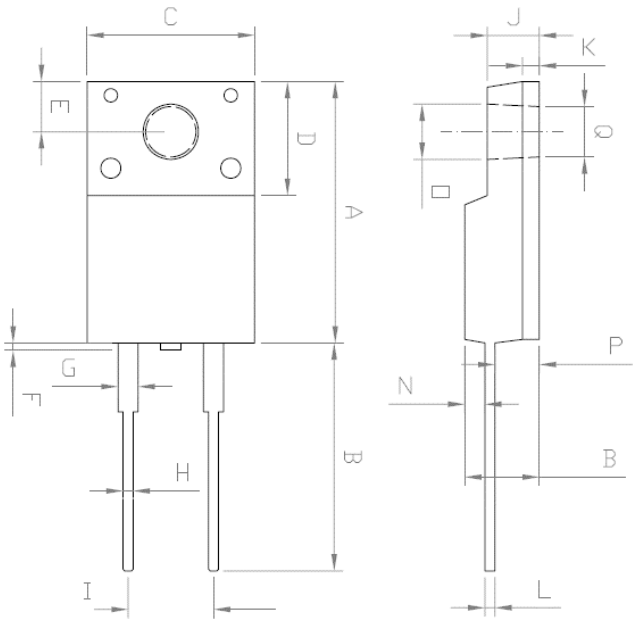


Fig. 7 Thermal Impedance

Package TO-220-2EP （Unit: mm）



REF.DIM	DATA BOOK mm		
	NOR	MIN	MAX
A	15.6	14.8	16.1
B	13	12.65	13.8
C	10	9.85	10.36
D	6.5	4.6	6.8
E	3.0	2.55	3.5
F			1
G	1.2	1	1.45
H	0.6	0.3	0.9
I	5.1	4.8	5.4
J	3.1	2.34	3.3
K	1.0	0.55	1.3
L	0.6	0.36	0.8
M	4.45	4.2	4.9
N	1.2	1.1	1.8
O	3.3	2.9	3.5
P	2.6	2.5	3.15
Q	3	2.9	3.5

This Product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, systems, or air-traffic control systems.

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. With respect to any examples, hints or any typical values stated herein and/or any information regarding the application of the product, Hycores Inc. disclaims any and all warranties and liabilities of any kind, including without limitation warranties of non-infringement of intellectual property rights of any third party.

HyCores